NSN 5961-01-318-5976

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View Online at https://aerobasegroup.com/nsn/5961-01-318-5976 **Inclosure Material:** Metal **Overall Length:** 0.660 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.256 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 collector to base voltage/static/emitter open and 20.0 collector to emitter voltage/static/base open and 3.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 70.0 watts small-signal input power, common-collector absolute **Transfer Ratio:** 10.0 static forward current transfer ratio, common-emitter and 100.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 4 ribbon Shelf Life: N/a

Demilitarization: No

Unit Of Measure:

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